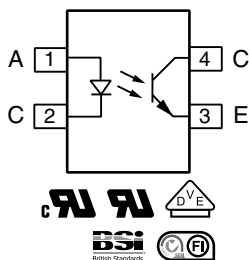
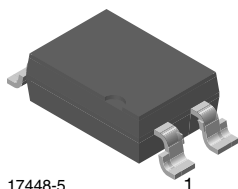


**Optocoupler, Phototransistor Output, High Reliability, 5300 V_{RMS}****DESCRIPTION**

The SFH615A-3X018T features a variety of transfer ratios, low coupling capacitance and high isolation voltage. This coupler has a GaAs infrared diode emitter, which is optically coupled to a silicon planar phototransistor detector, and is incorporated in a plastic SMD package.

The coupling devices are designed for signal transmission between two electrically separated circuits.

FEATURES

- Excellent CTR linearity depending on forward current
- Isolation test voltage, 5300 V_{RMS}
- Fast switching times
- Low CTR degradation
- Low coupling capacitance
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

RoHS
COMPLIANT**APPLICATIONS**

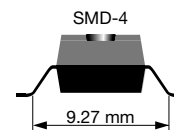
- Switchmode power supply
- Telecom
- Battery powered equipment

AGENCY APPROVALS

- UL1577, file no. E52744 system code H or J, double protection
- DIN EN 60747-5-5 (VDE 0884-5) available with option 1
- cUL tested to CSA 22.2 bulletin 5A
- BSI IEC 60950, IEC 60065
- FIMKO EN6005, EN60950-1

ORDERING INFORMATION

S	F	H	6	1	5	A	-	3	X	0	1	8	T
PART NUMBER								CTR BIN	PACKAGE OPTION				TAPE AND REEL



AGENCY CERTIFIED/PACKAGE	CTR (%)
	10 mA
VDE, UL, cUL, BSI, FIMKO	100 to 200
SMD-4, option 8	SFH615A-3X018T

ABSOLUTE MAXIMUM RATINGS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
INPUT				
Reverse voltage		V_R	6	V
DC forward current		I_F	60	mA
Surge forward current	$t_p \leq 10\text{ }\mu\text{s}$	I_{FSM}	2.5	A
OUTPUT				
Collector emitter voltage		V_{CEO}	70	V
Emitter collector voltage		V_{ECO}	7	V
Collector current		I_C	50	mA
	$t_p \leq 1\text{ ms}$	I_C	100	mA
COUPLER				
Isolation test voltage between emitter and detector	$t = 1\text{ s}$	V_{ISO}	5300	V_{RMS}
Creepage distance			≥ 7	mm
Clearance distance			≥ 7	mm
Insulation thickness between emitter and detector			≥ 0.4	mm
Comparative tracking index per DIN IEC112/VDE0303 part 1		CTI	≥ 175	
Isolation resistance	$V_{IO} = 500\text{ V}, T_{amb} = 25\text{ }^{\circ}\text{C}$	R_{IO}	$\geq 10^{12}$	Ω
	$V_{IO} = 500\text{ V}, T_{amb} = 100\text{ }^{\circ}\text{C}$	R_{IO}	$\geq 10^{11}$	Ω
Storage temperature range		T_{stg}	- 55 to + 150	$^{\circ}\text{C}$
Ambient temperature range		T_{amb}	- 55 to +100	$^{\circ}\text{C}$
Soldering temperature ⁽¹⁾	max. 10 s	T_{sld}	260	$^{\circ}\text{C}$

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

⁽¹⁾ Refer to reflow profile for soldering conditions for surface mounted devices (SMD).

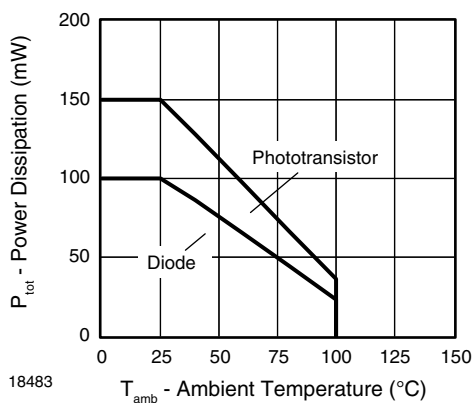
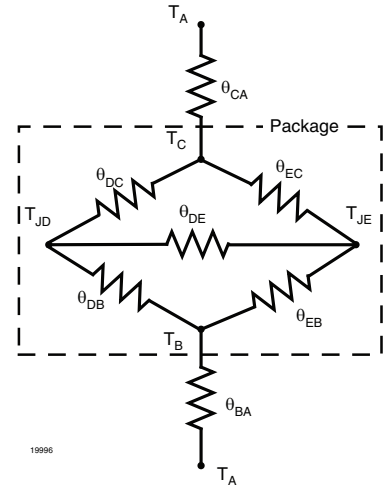


Fig. 1 - Permissible Power Dissipation vs. Ambient Temperature

THERMAL CHARACTERISTICS

PARAMETER	SYMBOL	VALUE	UNIT
LED power dissipation	P_{diss}	100	mW
Output power dissipation	P_{diss}	150	mW
Maximum LED junction temperature	$T_{jmax.}$	125	°C
Maximum output die junction temperature	$T_{jmax.}$	125	°C
Thermal resistance, junction emitter to board	θ_{EB}	173	°C/W
Thermal resistance, junction emitter to case	θ_{EC}	149	°C/W
Thermal resistance, junction detector to board	θ_{DB}	111	°C/W
Thermal resistance, junction detector to case	θ_{DC}	127	°C/W
Thermal resistance, junction emitter to junction detector	θ_{ED}	95	°C/W
Thermal resistance, board to ambient ⁽¹⁾	θ_{BA}	195	°C/W
Thermal resistance, case to ambient ⁽¹⁾	θ_{CA}	3573	°C/W


Notes

- The thermal model is represented in the thermal network below. Each resistance value given in this model can be used to calculate the temperatures at each node for a given operating condition. The thermal resistance from board to ambient will be dependent on the type of PCB, layout and thickness of copper traces. For a detailed explanation of the thermal model, please reference Vishay's thermal characteristics of optocouplers application note.

⁽¹⁾ For 2 layer FR4 board (4" x 3" x 0.062")

ELECTRICAL CHARACTERISTICS ($T_{amb} = 25\text{ °C}$, unless otherwise specified)

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT						
Forward voltage	$I_F = 60\text{ mA}$	V_F		1.25	1.65	V
Reverse current	$V_R = 6\text{ V}$	I_R		0.01	10	μA
Capacitance	$V_R = 0\text{ V}, f = 1\text{ MHz}$	C_O		13		pF
OUTPUT						
Collector emitter capacitance	$V_{CE} = 5\text{ V}, f = 1\text{ MHz}$	C_{CE}		5.2		pF
Collector emitter leakage current	$V_{CE} = 10\text{ V}$	I_{CEO}		5	100	nA
COUPLER						
Collector emitter saturation voltage	$I_F = 10\text{ mA}, I_C = 2.5\text{ mA}$	V_{CEsat}		0.25	0.4	V
Coupling capacitance		C_C		0.4		pF

Note

- Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
I_C/I_F	$I_F = 10\text{ mA}, V_{CE} = 5\text{ V}$	CTR	100		200	%
	$I_F = 1\text{ mA}, V_{CE} = 5\text{ V}$	CTR	34	70		%

**SWITCHING CHARACTERISTICS**

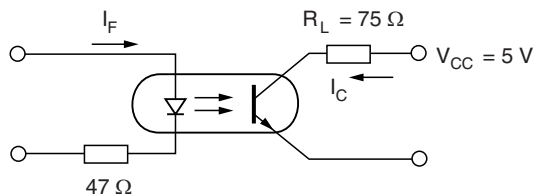
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
NON-SATURATED						
Rise time	$I_F = 10\text{ mA}$, $V_{CC} = 5\text{ V}$, $T_A = 25\text{ °C}$, $R_L = 75\text{ }\Omega$	t_r		2		μs
Fall time	$I_F = 10\text{ mA}$, $V_{CC} = 5\text{ V}$, $T_A = 25\text{ °C}$, $R_L = 75\text{ }\Omega$	t_f		2		μs
Turn-on time	$I_F = 10\text{ mA}$, $V_{CC} = 5\text{ V}$, $T_A = 25\text{ °C}$, $R_L = 75\text{ }\Omega$	t_{on}		3		μs
Turn-off time	$I_F = 10\text{ mA}$, $V_{CC} = 5\text{ V}$, $T_A = 25\text{ °C}$, $R_L = 75\text{ }\Omega$	t_{off}		2.3		μs
Cut-off frequency	$I_F = 10\text{ mA}$, $V_{CC} = 5\text{ V}$, $T_A = 25\text{ °C}$, $R_L = 75\text{ }\Omega$	f_{ctr}		250		kHz
SATURATED						
Rise time	$V_{CC} = 5\text{ V}$, $T_A = 25\text{ °C}$, $R_L = 1\text{ k}\Omega$, $I_F = 10\text{ mA}$	t_r		3		μs
Fall time	$V_{CC} = 5\text{ V}$, $T_A = 25\text{ °C}$, $R_L = 1\text{ k}\Omega$, $I_F = 10\text{ mA}$	t_f		14		μs
Turn-on time	$V_{CC} = 5\text{ V}$, $T_A = 25\text{ °C}$, $R_L = 1\text{ k}\Omega$, $I_F = 10\text{ mA}$	t_{on}		4.2		μs
Turn-off time	$V_{CC} = 5\text{ V}$, $T_A = 25\text{ °C}$, $R_L = 1\text{ k}\Omega$, $I_F = 10\text{ mA}$	t_{off}		23		μs

SAFETY AND INSULATION RATINGS

PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Climatic classification (according to IEC 68 part 1)				55/100/21		
Comparative tracking index		CTI	175		399	
V_{IOTM}		V_{IOTM}	10 000			V_{peak}
V_{IORM}		V_{IORM}	890			V_{peak}
P_{SO}		P_{SO}			400	mW
I_{SI}		I_{SI}			275	mA
T_{SI}		T_{SI}			175	°C
Creepage distance			7			mm
Clearance distance			7			mm
Insulation thickness, reinforced rated	per IEC 60950 2.10.5.1		0.4			mm

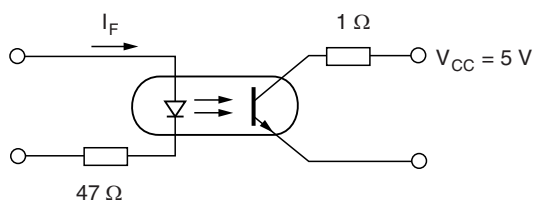
Note

- As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for “safe electrical insulation” only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

TYPICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)


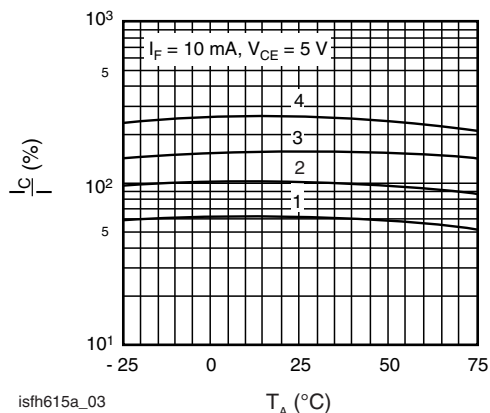
isfh615a_01

Fig. 2 - Linear Operation (without Saturation)



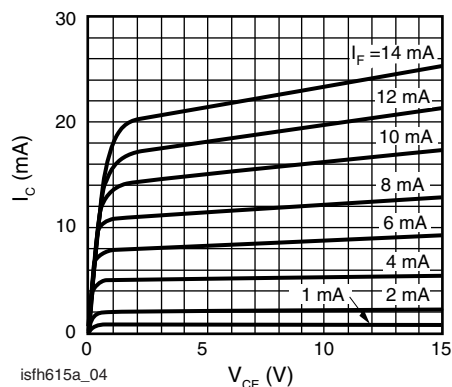
isfh615a_02

Fig. 3 - Switching Operation (with Saturation)



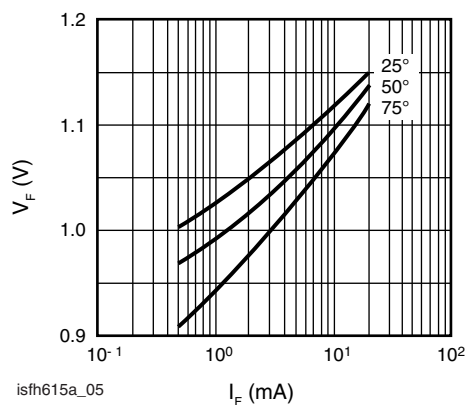
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Fig. 4 - Current Transfer Ratio (Typ.) vs. Temperature



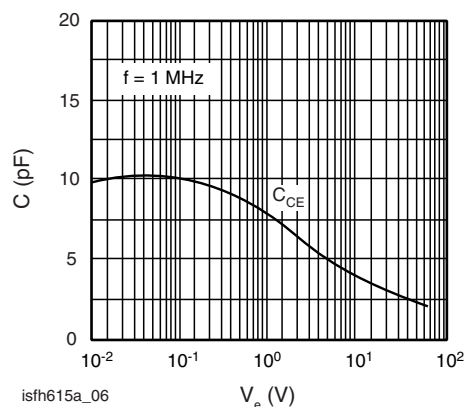
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Fig. 5 - Output Characteristics (Typ.) Collector Current vs. Collector Emitter Voltage



isfh615a_05

Fig. 6 - Diode Forward Voltage (Typ.) vs. Forward Current



isfh615a_06

Fig. 7 - Transistor Capacitance (Typ.) vs. Collector Emitter Voltage

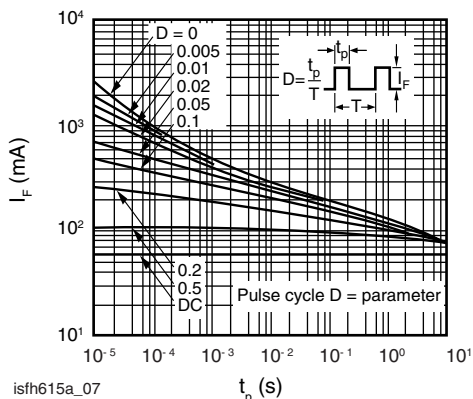
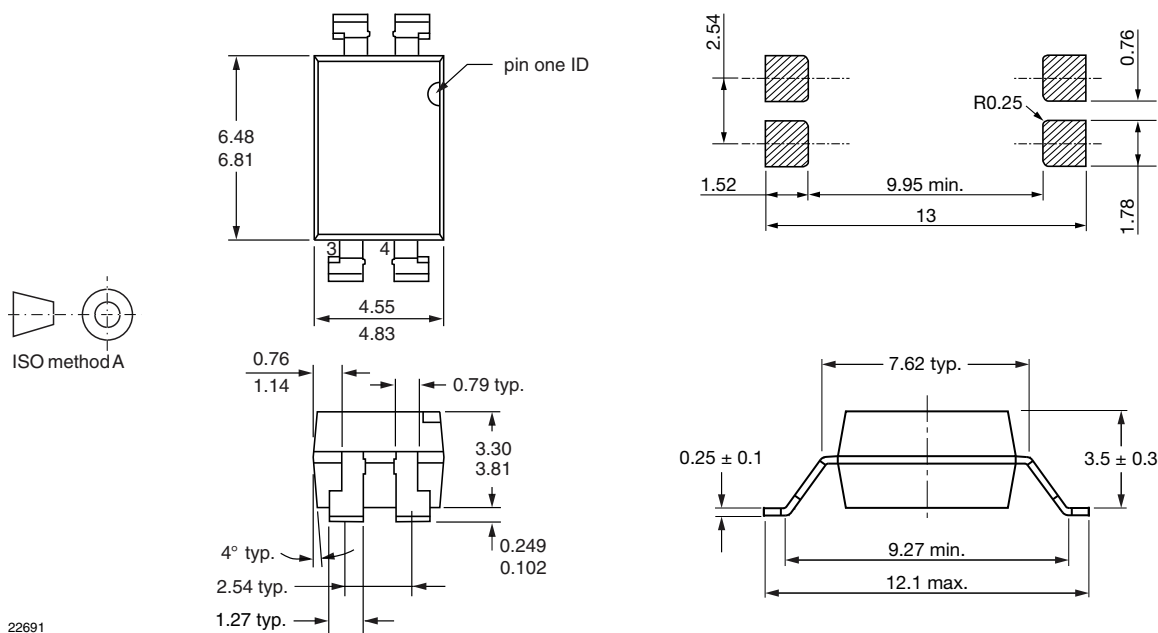
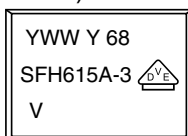


Fig. 8 - Permissible Pulse Handling Capability Forward Current vs. Pulse Width

PACKAGE DIMENSIONS millimeters



PACKAGE MARKING (example of SFH615A-3X018T)



Notes

- VDE logo is only marked on option 1 parts.
- Tape and reel suffix (T) is not part of the package marking.



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